

APPROVAL SHEET

MULTILAYER CERAMIC CAPACITORS

Microwave MLCC with Narrow-Tolerance (UF)

0201 & 0402 Sizes (25V to 100V)

NP0 Dielectric

Halogen Free & RoHS Compliance

*Contents in this sheet are subject to change without prior notice.

Approval Sheet

1. INTRODUCTION

MLCC consists of a conducting material and electrodes. To manufacture a chip-type SMT and achieve miniaturization, high density and high efficiency, ceramic condensers are used.

WTC UF series MLCC is used at high frequencies generally have a small temperature coefficient of capacitance, typical within the ±30ppm/°C required for NP0 (C0G) classification, Ultra-narrow tolerance of capacitance and have excellent conductivity internal electrode. Thus, WTC UF series MLCC will be with the feature of low ESR and high Q characteristics.

2. FEATURES

- a. High Q and low ESR performance at high frequency.
- b. Ultra low capacitance to 0.05pF.
- c. Can offer ultra-narrow tolerance to ±0.02pF.
- d. Quality improvement of telephone calls for low power loss and better performance.

3. APPLICATIONS

- a. Telecommunication products & equipments: Mobile phone, WLAN, Base station.
- b. RF module: Power amplifier, VCO.
- c. Tuners.

4. HOW TO ORDER

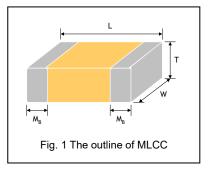
<u>UF</u>	<u>15</u>	<u>N</u>	<u>R05</u>	<u>P</u>	<u>250</u>	<u>C</u>	Ī
<u>Series</u>	Size	Dielectric	Capacitance	Tolerance	Rated voltage	<u>Termination</u>	<u>Packaging</u>
UF= Microwave MLCC with narrow-tolerance	03 =0201 (0603) 15 =0402 (1005)	8	Two significant digits followed by no. of zeros. And R is in place of decimal point.	P=±0.02pF Q=±0.03pF A=±0.05pF B=±0.1pF	Two significant digits followed by no. of zeros. And R is in place of decimal point.	C =Cu/Ni/Sn	T=7" reeled G= 13" reeled
			eg.: R05=0.05pF 0R5=0.5pF 1R0=1.0pF	Cap. ≥10pF F=±1% G=±2%	250=25 VDC 500=50 VDC 101=100 VDC		



5. EXTERNAL DIMENSIONS

Size Inch (mm)	L (mm)	W (mm)	T (mm)/Sym	bol	Remark	M _B (mm)
0201 (0603)	0.60±0.03	0.30±0.03	0.30±0.03	L	#	0.15±0.05
0402 (1005)	1.00±0.05	0.50±0.05	0.50±0.05	N	#	0.25+0.05/-0.10

[#] Reflow soldering only is recommended.



6. GENERAL ELECTRICAL DATA

Dielectric	NP0			
Size	0201, 0402			
Capacitance*	0.05pF to 10pF			
Capacitance tolerance	P (±0.02pF), Q (±0.03pF), A (±0.05pF), B (±0.1pF), Cap≥10pF: F (±1%), G (±2%)			
Rated voltage (WVDC)	25V, 50V, 100V			
Q**	Q≥400+20C			
Insulation resistance at Ur	≥10GΩ or RxC≥100Ω-F whichever is smaller.			
Operating temperature	-55 to +125°C - X IX IX			
Capacitance change	±30ppm/°C			
Termination	Ni/Sn (lead-free termination)			

^{**} Measured at the conditions of 25°C ambient temperature and 30~70% related humidity. Apply 1.0±0.2Vrms, 1.0MHz±10%

7. PACKAGING DIMENSION AND QUANTITY

Size	Thickness (mm)/Symbol	Paper tape		
Size	Thickness (mm)/Symbol	7" reel	13" reel	
0201 (0603)	0.30±0.03	15,000	70,000	
0402 (1005)	0.50±0.05	10,000	50,000	

PASSIVE SYSTEM ALLIANCE

Unit: pieces



8. CAPACITANCE RANGE

DIELECTRIC				NP	0		
	SIZE	0201			0402		
RAT	ED VOLTAGE (VDC)	25	50	100	25 50		- Tolerance
	0.05pF (R05)	L	L		N	N	P, Q, A
	0.1pF (0R1)	L	L	L*	N	N	P, Q, A
	0.2pF (0R2)	L	L	L*	N	N	P, Q, A
	0.3pF (0R3)	L	L	L*	N	N	P, Q, A
	0.4pF (0R4)	L	L	L*	N	N	P, Q, A
	0.5pF (0R5)	L	L	L*	N	N	P, Q, A
	0.6pF (0R6)	L	L	L*	N	N	P, Q, A
	0.7pF (0R7)	L	L	L*	N	N	P, Q, A
	0.8pF (0R8)	L	L	L*	N	N	P, Q, A
	0.9pF (0R9)	L	L	L*	N	N	P, Q, A
	1.0pF (1R0)	L	L	L*	N	N	P, Q, A
	1.1pF (1R1)	L	L	L	N	N	P, Q,A, B
	1.2pF (1R2)	L	L	L	N	N	P, Q,A, B
	1.3pF (1R3)	L	L	L	N	N	A, B
	1.5pF (1R5)	L	L	L	N	N	A, B
	1.6pF (1R6)	L	L	L	N	N	A, B
	1.8pF (1R8)	L	L	L	N	N	A, B
	2.0pF (2R0)	L	L	L	N	N	A, B
	2.2pF (2R2)	L	L	乙石	15 N	N	A, B
မွ	2.4pF (2R4)	L	上、过度	PI I	D SN	N	A, B
Capacitance	2.7pF (2R7)	L	LTREE	LX LLI	N	N	A, B
acit	3.0pF (3R0)	L	//R	XXIXI	N	N	A, B
ар	3.3pF (3R3)	L	J. J	L	177		A, B
0	3.6pF (3R6)	L	THE LAW	L	(-) 3,1		A, B
	3.9pF (3R9)	L	114 A	L			A, B
	4.0pF (4R0)	L	Ľ"				A, B
	4.3pF (4R3)	L	L	STVE SYSTEM	ALLIANCE		A, B
	4.7pF (4R7)	L	84	L			A, B
	5.0pF (5R0)	L	姜 5	L	2 2		A, B
	5.1pF (5R1)	L	9 6	L	10 25	7	A, B
	5.6pF (5R6)	L .	(OL)	L			A, B
	6.0pF (6R0)	L		Chilono	(0) (1)		A, B
	6.2pF (6R2)	L		CUDIOS	1011		A, B
	6.7pF (6R7)	L .	1 /2(MOINGY CODE	UBY/////		A, B
	6.8pF (6R8)	L	L	THOLOUY CURY	VI.		A, B
	7.0pF (7R0)	L	L .	L			A, B
	7.5pF (7R5)	L	L	L			A, B
	8.0pF (8R0)	L	L	L			A, B
	8.2pF (8R2)	L L	L	L			A, B
	9.0pF (9R0)	L	L	L			A, B
	9.1pF (9R1)	L	L	L			A, B
	9.9pF (9R9)	L	L	L			A, B
	10pF (100)	L	L	L			F,G,J

^{1.} The letter in cell is expressed the symbol of product thickness.

^{2.} The letter in cell with " * " mark is expressed product not in "P"&"Q" tolerance; "A" tolerance only.

^{3.} For more information about products with special capacitance or other data, please contact WTC local representative.

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9. RELIABILITY TEST CONDITIONS AND REQUIREMENTS

No.	Item	Test Conditions	Requirements
1.	Visual and		* No remarkable defect.
	Mechanical		* Dimensions to conform to individual specification sheet.
2.	Capacitance	* Test temp.: Room Temperature.	* Shall not exceed the limits given in the detailed spec.
3.	Q/ D.F.	1.0±0.2Vrms, 1MHz±10%	* Cap.=0.05pF: Q≥300
	(Dissipation		* 0.1pF≤Cap.<30pF: Q≥400+20C
	Factor)		
4.	Dielectric	*To apply voltage: 250% of rated voltage.	* No evidence of damage or flash over during test.
	Strength	*Duration: 1 to 5 sec.	
		*Charge & discharge current less than 50mA.	
5.	Insulation	* Test temp.: Room Temperature.	≥10GΩ or RxC≥100Ω-F whichever is smaller
	Resistance	* To apply rated voltage for max. 120 sec.	
6.	Temperature	With no electrical load.	* Capacitance change: within ±30ppm/°C;
	Coefficient	Operating temperature: -55~125°C at 25°C	
7.	Adhesive	* Pressurizing force :	* No remarkable damage or removal of the terminations.
	Strength of	0201: 2N	
	Termination	0402: 5N	
		* Test time: 10±1 sec.	2' 125
8.	Vibration	* Vibration frequency: 10~55 Hz/min.	* No remarkable damage.
	Resistance	* Total amplitude: 1.5mm	* Cap change and Q/D.F.: To meet initial spec.
		* Test time: 6 hrs. (Two hrs each in three mutually	(=> 50)
		perpendicular directions.)	TILL
		*Cap./DF(Q) Measurement to be made after de-aging at 150°C	
		for 1hr then set for 24±2 hrs at room temp.	IANCE
9.	Solderability	* Solder temperature: 235±5°C	95% min. coverage of all metalized area.
40		* Dipping time: 2±0.5 sec.	
10.	Bending Test	* The middle part of substrate shall be pressurized by means	* No remarkable damage.
		of the pressurizing rod at a rate of about 1 mm per second until	
		the deflection becomes 1 mm and then the pressure shall be maintained for 5±1 sec.	(This capacitance change means the change of capacitance under
		1//////	specified flexure of substrate from the capacitance measured before
		* Measurement to be made after keeping at room temp, for 24±2 hrs.	the test.)
11	Resistance to	* Solder temperature: 260±5°C	* No remarkable damage.
		* Dipping time: 10±1 sec	* Cap change: within ±2.5% or ±0.25pF whichever is larger.
	- Jidoning ricat	* Preheating: 120 to 150°C for 1 minute before immerse the	* Q/D.F., I.R. and dielectric strength: To meet initial requirements.
		capacitor in a eutectic solder.	* 25% max. leaching on each edge.
		*Cap. / DF(Q) / I.R. Measurement to be made after de-aging at	
		150°C for 1hr then set for 24±2 hrs at room temp.	

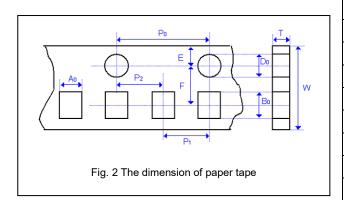
^{* &}quot;Room condition" Temperature: 15 to 35°C, Relative humidity: 25 to 75%, Atmospheric pressure: 86 to 106kPa.

No.	Item	Test Condition			Requir	rements	
12.	Temperature	* Conduc	t the five cycles according to the	temperatures and	* No remarkable damage.		
	Cycle	time.			* Cap change: within ±2.5% or ±0.25pF whichever is larger.		
		Step	Temp. (°C)	Time (min.)	* Q/D.F., I.R. and dielectric stren	igth: To meet initial requirements.	
		1	Min. operating temp. +0/-3	30±3			
		2	Room temp.	2~3			
		3	Max. operating temp. +3/-0	30±3			
		4	Room temp.	2~3			
		* Cap. / [OF(Q) / I.R. Measurement to be n	nade after de-aging at			
		150°C fo	r 1hr then set for 24±2 hrs at roor	m temp.			
13.	Humidity	* Test ter	np.: 40±2°C		* No second table description		
	(Damp Heat)	* Humidit	y: 90~95% RH		* No remarkable damage.	0.5=5tishis lanna	
	Steady State	* Test tim	e: 500+24/-0hrs.		* Cap change: within ±5.0% or ±	:0.5pF whichever is larger.	
		* Cap. / [OF(Q) / I.R. Measurement to be n	nade after de-aging at	* Q/D.F. value: Q≥200+10C		
		150°C fo	r 1hr then set for 24±2 hrs at roor	m temp.	* I.R.: ≥1GΩ.		
14.	Humidity	* Test ter	np.: 40±2°C	·	* No remarkable damage.		
	(Damp Heat)	* Humidit	y: 90~95%RH		* Cap change: within ±7.5% or ±0.75pF whichever is larger.		
	Load		e: 500+24/-0 hrs.		* Q/D.F. value: Q≥100+10/3C		
			y voltage: rated voltage		* I.R.; ≥500MΩ.		
		1	DF(Q) / I.R. Measurement to be n	nade after de-aging at			
		1	or 1hr then set for 24±2 hrs at roo				
15	High		np.: 125±3°C	LA 1	* No remarkable damage.		
	Temperature		y voltage: 200% of rated voltage.		* Cap change: within ±3.0% or ±0.3pF whichever is larger.		
	Load		e: 2000+24/-0 hrs.	"比船份>	* Q/D.F. value: Q≥200+10C	o.opi whichever is larger.	
	(Endurance)	1	DF(Q) / I.R. Measurement to be n	ando offer de eging et			
	(Elidurance)		r 1hr then set for 24±2 hrs at roo		1.11., 210Ω.		
16	ESR	1		•			
10.	ESK		should be measured at room ter	mperature and tested	0004	0.400	
		at freque	ncy 1±0.1 GHz.		0201	0402	
			PAS	SIVE SYSTEM ALL	0.05pF≤Cap≤1pF:< 350mΩ/pF	0.05pF≤Cap≤1pF:< 350mΩ/pF	
	OP 5		1pF <cap≤5pf:< 300mω<="" td=""><td>1pF<cap≤5pf:< 300mω<="" td=""></cap≤5pf:<></td></cap≤5pf:<>	1pF <cap≤5pf:< 300mω<="" td=""></cap≤5pf:<>			
				5pF <cap≤22pf:< 250mω="" 250mω<="" 5pf<cap≤100pf:<="" td="" =""></cap≤22pf:<>			
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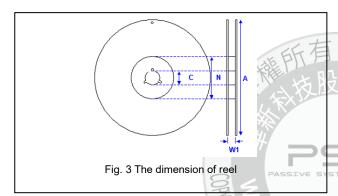
 $^{^{\}star}$ "Room condition" Temperature: 15 to 35°C, Relative humidity: 25 to 75%, Atmospheric pressure: 86 to 106kPa.

APPENDIXES

■ Tape & reel dimensions



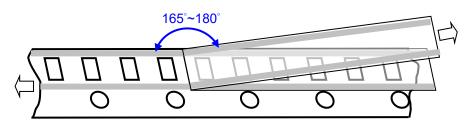
Size	0201	0402
Thickness	L	N
A ₀	0.40 +/-0.10	0.70 +/-0.20
B ₀	0.70 +/-0.10	1.20 +/-0.20
Т	≦0.55	≦0.80
K ₀	-	-
w	8.00 +/-0.30	8.00 +/-0.30
P ₀	4.00 +/-0.10	4.00 +/-0.10
10xP₀	40.00 +/-0.10	40.00 +/-0.10
P ₁	2.00 +/-0.05	2.00 +/-0.05
P ₂	2.00 +/-0.05	2.00 +/-0.05
D ₀	1.50 +0.1/-0	1.50 +0.1/-0
D ₁	-	-
E	1.75 +/-0.10	1.75 +/-0.10
Z F	3.50 +/-0.05	3.50 +/-0.05



Size	0201, 0402			
Reel size	7"	13"		
С	13.0±0.5	13.0±0.5		
W ₁	10.0±1.5	10.0±1.5		
Α	178.0±2.0	330.0±2.0		
N	60.0+1.0/-0	50 min		

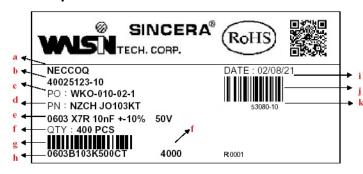
■ Peeling force (EIA-481)

Peel-off force should be in the range of 10 grams to 100 grams at a peel-off speed of 300±10 mm/min.



Approval Sheet

■ Example of customer label

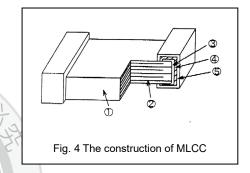


^{*}Customized label is available upon request

- a. Customer name
- b. WTC order series and item number
- c. Customer P/O
- d. Customer P/N
- e. Description of product
- f. Quantity
- g. Bar code including quantity & WTC P/N or customer
- h. WTC P/N
- i. Shipping date
- j. Order bar code including series and item numbers
- k. Serial number of label

Constructions

No.	Na	NP0	
1	Ceramic	Hi-Q dielectric ceramic	
2	Inner e	Cu	
3		Inner layer	Cu
4	Termination	Middle layer	Ni
5		Outer layer	Sn (Matt)





Storage and handling conditions

- (1) To store products at 5 to 40°C ambient temperature and 20 to 70%, related humidity conditions; MSL Level 1.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

Cautions:

- a. The corrosive gas reacts on the terminal electrodes of capacitors, and results in the poor solderability. Do not store the capacitors in the ambience of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
- b. In corrosive atmosphere, solderability might be degraded, and silver migration might occur to cause low reliability.
- c. Due to the dewing by rapid humidity change, or the photochemical change of the terminal electrode by direct sunlight, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or dewing condition. To store products on the shelf and avoid exposure to moisture.

■ Recommended soldering conditions

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of N₂ within oven are recommended.

